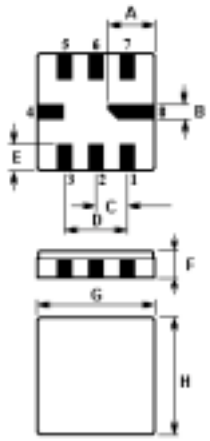
The LGER550 is a true one-port，surface-acoustic-wave (**SAW**) resonator in a surface-mount ceramic **QCC8C** case**.** It provides reliable， fundamental-mode， quartz frequency stabilization of fixed-frequency transmitters operating at **433.920 MHz.**

1.Package Dimension (QCC8C)



Pin	Connection
2	Input / Output
6	Output / Input
4,8	Case Ground
1,3,5,7	Empty

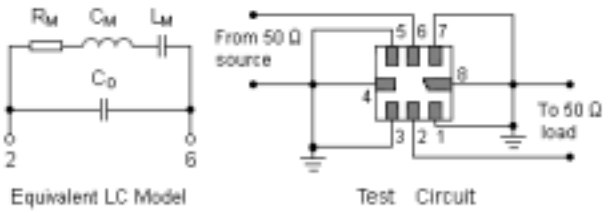
Sign	Data (unit: mm)	Sign	Data(unit:mm)
A	2.08	E	1.20
B	0.60	F	1.35
C	1.27	G	5.00
D	2.54	H	5.00

2.Marking

LGER550

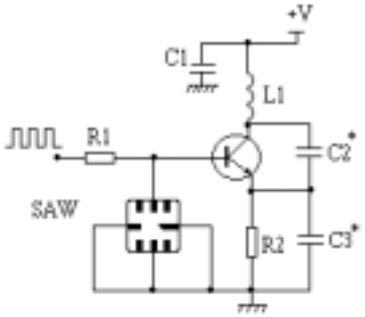
Color: Black or Blue

3.Equivalent LC Model and Test Circuit

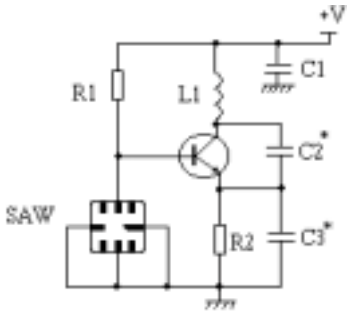


4.Typical Application Circuit

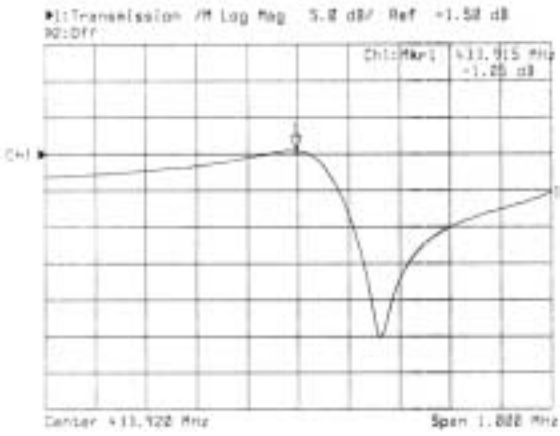
1) Telecontrol Circuitry



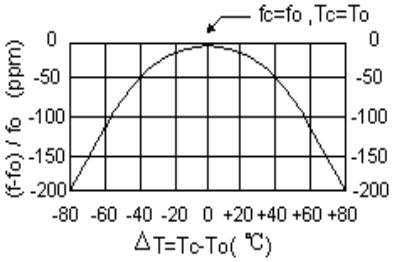
2) Local Oscillator Application



5.Typical Frequency Response



6.Temperature Characteristics



The curve shown above accounts for resonator contribution only and does not include oscillator temperature characteristics.

7.Performance

7-1.Maximum Ratings

Rating	Value	Units
CW RF Power Dissipation	+10	dBm
DC Voltage Between Any Two Pins	±30V	VDC
Case Temperature	-40 to +85	℃
Soldering Temperature	+235	℃

7-2.Electronic Characteristics

Characteristic		Sym	Minimum	Typical	Maximum	Units
Center Frequency (+25℃)	Absolute Frequency	f_C	433.845		433.995	MHz
	Tolerance from 433.920 MHz	Δf_C		±75		kHz
Insertion Loss		IL		1.3	2.0	dB
Quality Factor	Unloaded Q	Q_U		10,500		
	50 Ω Loaded Q	Q_L		1,450		
Temperature Stability	Turnover Temperature	T_O	25	40	55	℃
	Turnover Frequency	f_O		fc		kHz
	Frequency Temperature Coefficient	FTC		0.037		ppm/℃^{2}
Frequency Aging	Absolute Value during the First Year	$\|f_A\|$		≤10		ppm/yr
DC Insulation Resistance Between Any Two Pins			1.0			MΩ
RF Equivalent RLC Model	Motional Resistance	R_M		16	26	Ω
	Motional Inductance	L_M		61.724		μH
	Motional Capacitance	C_M		2.1817		fF
	Pin 2 to Pin 6 Static Capacitance	C_O	1.9	2.2	2.5	pF

☺ **CAUTION: Electrostatic Sensitive Device. Observe precautions for handling !**

NOTES:

1. Frequency aging is the change in f_C with time and is specified at +65℃or less. Aging may exceed the specification for prolonged temperatures above +65℃. Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
2. The center frequency, f_C ,is the frequency of minimum IL measured with the resonator in the specified test fixture in a 50 Ω test system with VSWR ≤ 1.2 : 1. Typically, $f_{oscillator}$ or $f_{transmitter}$ is approximately equal to the resonator f_C.
3. Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
4. Unless noted otherwise , case temperature T_C=+25℃±2℃.
5. The design, manufacturing process, and specifications of this device are subject to change without notice.
6. Derived mathematically from one or more of the following directly measured parameters: f_C, IL, 3 dB bandwidth, f_C versus T_C , and C_O.
7. Turnover temperature, T_O, is the temperature of maximum (or turnover) frequency, f_O. The nominal center frequency at any case temperature , T_C, may be calculated from :$f = f_O [1\text{-FTC } (T_O\text{-}T_C)^2]$ .Typically, oscillator T_O is approximately equal to the specified resonator T_O.
8. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only . The capacitance C_O is the static (nonmotional) capacitance between the two terminals measured at low frequency (10MHz) with a capacitance meter. Case parasitic capacitance is approximately 0.05pF.Transducer parallel capacitance can by calculated as: $C_P = C_O$ - 0.05pF.